BUK9615-100A

N-channel TrenchMOS logic level FET

Rev. 3 — 19 April 2011 Product data sheet

1. Product profile

1.1 General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

1.2 Features and benefits

- AEC Q101 compliant
- Low conduction losses due to low on-state resistance

1.3 Applications

- Automotive and general purpose power switching

1.4 Quick reference data

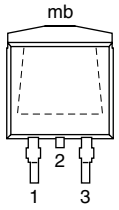
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25$ °C; $T_j \leq 175$ °C	-	-	100	V
I_D	drain current	$T_{mb} = 25$ °C	-	-	75	A
P_{tot}	total power dissipation		-	-	230	W
T_j	junction temperature		-55	-	175	°C
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10$ V; $I_D = 25$ A; $T_j = 25$ °C	-	11.5	14.4	mΩ
		$V_{GS} = 5$ V; $I_D = 25$ A; $T_j = 25$ °C	-	12	15	mΩ
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$I_D = 35$ A; $V_{sup} \leq 25$ V; $R_{GS} = 50$ Ω; $V_{GS} = 5$ V; $T_{j(init)} = 25$ °C; unclamped	-	-	120	mJ

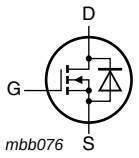
2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain		
3	S	source		
mb	D	mounting base; connected to drain		



SOT404 (D2PAK)



3. Ordering information

Table 3. Ordering information

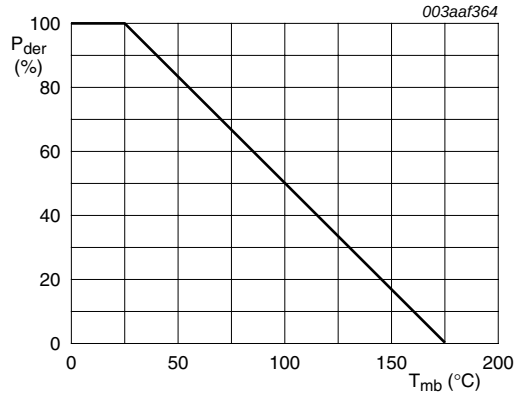
Type number	Package		
	Name	Description	Version
BUK9615-100A	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404

4. Limiting values

Table 4. Limiting values

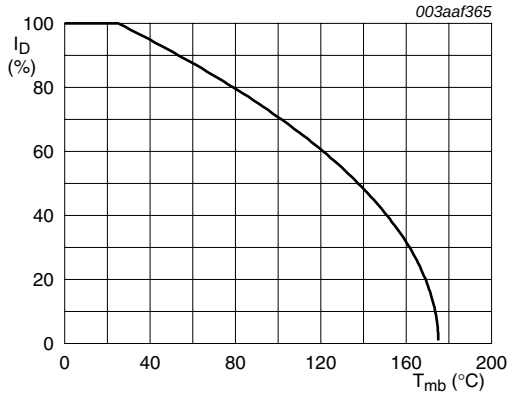
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25$ °C; $T_j \leq 175$ °C	-	100	V
V_{DGR}	drain-gate voltage	R_{GS} = 20 kΩ	-	100	V
V_{GS}	gate-source voltage		-10	10	V
I_D	drain current	T_{mb} = 25 °C	-	75	A
		T_{mb} = 100 °C	-	53	A
I_{DM}	peak drain current	T_{mb} = 25 °C; pulsed	-	313	A
P_{tot}	total power dissipation	T_{mb} = 25 °C	-	230	W
T_{stg}	storage temperature		-55	175	°C
T_j	junction temperature		-55	175	°C
V_{GSM}	peak gate-source voltage	pulsed; $t_p \leq 50$ µs	-15	15	V
Source-drain diode					
I_S	source current	T_{mb} = 25 °C	-	75	A
I_{SM}	peak source current	pulsed; T_{mb} = 25 °C	-	313	A
Avalanche ruggedness					
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	I_D = 35 A; $V_{sup} \leq 25$ V; R_{GS} = 50 Ω; V_{GS} = 5 V; $T_{j(init)}$ = 25 °C; unclamped	-	120	mJ



$$P_{der} = \frac{P_{tot}}{P_{tot(25°C)}} \times 100\,\%$$

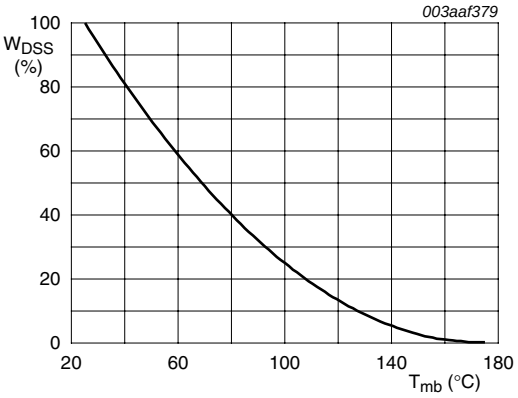
Fig 1. Normalized total power dissipation as a function of mounting base temperature



$$I_{der} = \frac{I_D}{I_{D(25°C)}} \times 100\,\%$$

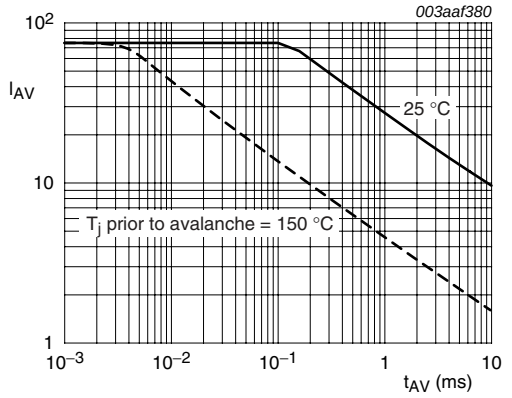
$V_{GS} \geq 5$ V

Fig 2. Normalized continuous drain current as a function of mounting base temperature



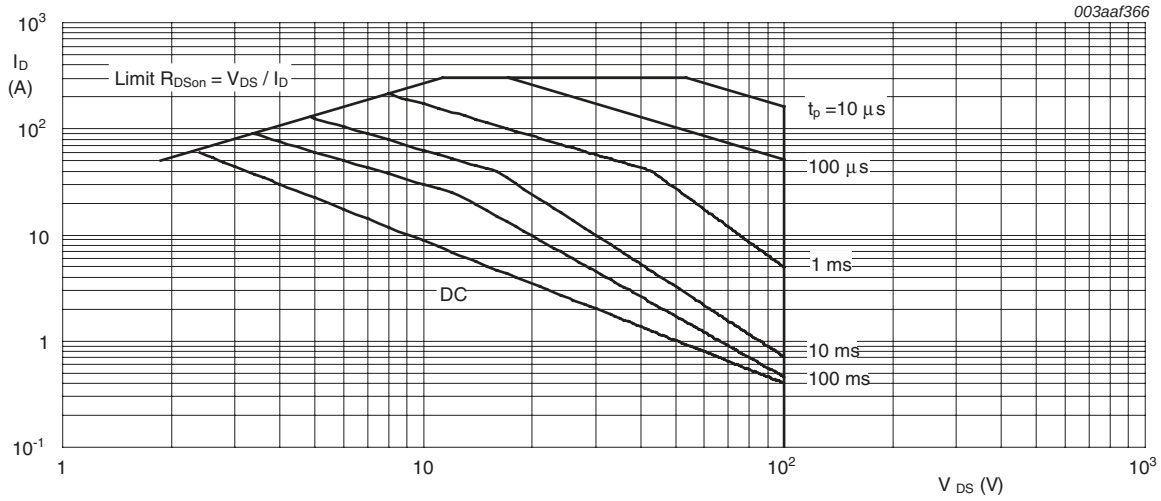
I_D = 75 A

Fig 3. Normalised drain-source non-repetitive avalanche energy as a function of mounting-base temperature



unclamped inductive load

Fig 4. Single-shot avalanche rating; avalanche current as a function of avalanche period



T_{mb} = 25 °C; I_{DM} is single pulse

Fig 5. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base		-	-	0.65	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	minimum footprint; FR4 board	-	50	-	K/W

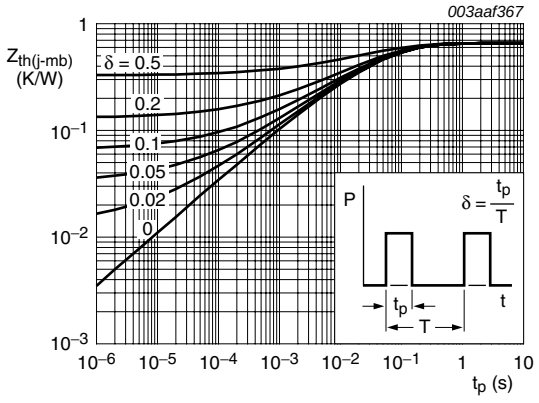
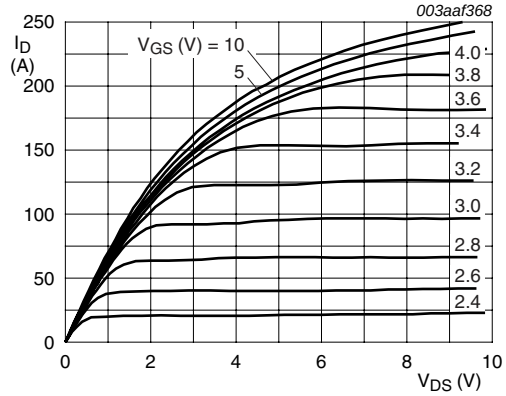


Fig 6. Transient thermal impedance from junction to mounting base as a function of pulse duration

6. Characteristics

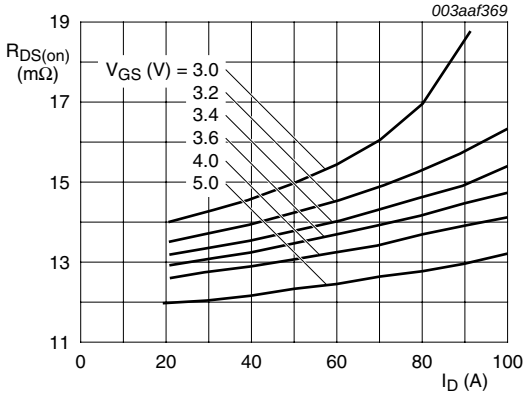
Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
$V_{(BR)DSS}$	drain-source breakdown voltage	I_D = 0.25 mA; V_{GS} = 0 V; T_j = 25 °C	100	-	-	V
		I_D = 0.25 mA; V_{GS} = 0 V; T_j = -55 °C	89	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25 °C	1	1.5	2	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55 °C	-	-	2.3	V
		I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175 °C	0.5	-	-	V
I_{DSS}	drain leakage current	V_{DS} = 100 V; V_{GS} = 0 V; T_j = 175 °C	-	-	500	µA
		V_{DS} = 100 V; V_{GS} = 0 V; T_j = 25 °C	-	0.05	10	µA
I_{GSS}	gate leakage current	V_{GS} = 10 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
		V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	2	100	nA
R_{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C	-	-	16	mΩ
		V_{GS} = 5 V; I_D = 25 A; T_j = 175 °C	-	-	40.5	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C	-	11.5	14.4	mΩ
		V_{GS} = 5 V; I_D = 25 A; T_j = 25 °C	-	12	15	mΩ
Dynamic characteristics						
C_{iss}	input capacitance	V_{GS} = 0 V; V_{DS} = 25 V; f = 1 MHz; T_j = 25 °C	-	6500	8600	pF
C_{oss}	output capacitance		-	550	660	pF
C_{rss}	reverse transfer capacitance		-	325	400	pF
$t_{d(on)}$	turn-on delay time	V_{DS} = 30 V; R_L = 1.2 Ω; V_{GS} = 5 V; $R_{G(ext)}$ = 10 Ω; T_j = 25 °C	-	45	65	ns
t_r	rise time		-	130	195	ns
$t_{d(off)}$	turn-off delay time		-	400	560	ns
t_f	fall time		-	130	190	ns
L_D	internal drain inductance	measured from upper edge of drain tab to centre of die; T_j = 25 °C	-	2.5	-	nH
		measured from drain lead 6 mm from package to centre of die; T_j = 25 °C	-	4.5	-	nH
L_S	internal source inductance	measured from source lead to source bond pad; T_j = 25 °C	-	7.5	-	nH
Source-drain diode						
V_{SD}	source-drain voltage	I_S = 75 A; V_{GS} = 0 V; T_j = 25 °C	-	1.1	-	V
		I_S = 25 A; V_{GS} = 0 V; T_j = 25 °C	-	0.85	1.2	V
t_{rr}	reverse recovery time	I_S = 75 A; dI_S/dt = -100 A/µs; V_{GS} = -10 V; V_{DS} = 30 V; T_j = 25 °C	-	60	-	ns
Q_r	recovered charge		-	0.24	-	µC



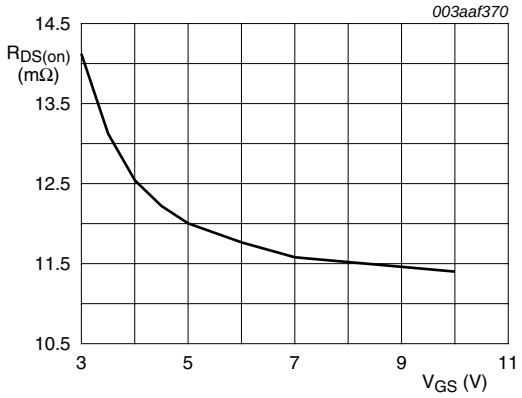
T_j = 25 °C

Fig 7. Output characteristics: drain current as a function of drain-source voltage; typical values



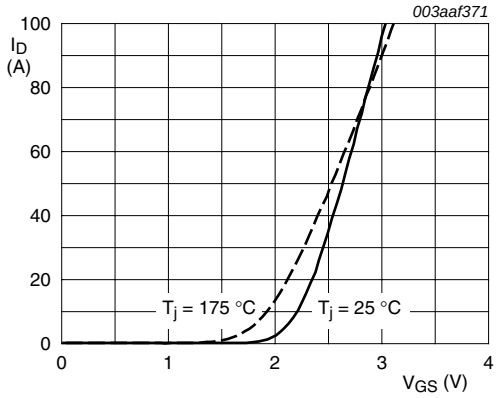
T_j = 25 °C

Fig 8. Drain-source on-state resistance as a function of drain current; typical values



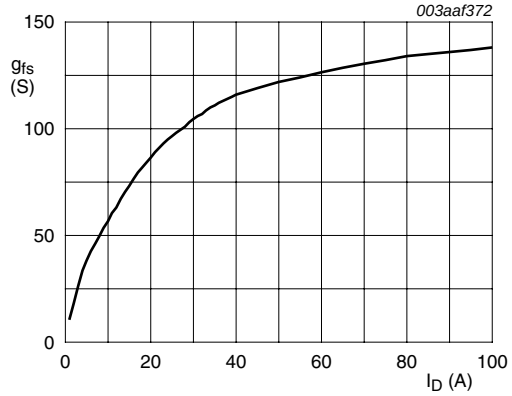
T_j = 25 °C

Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values



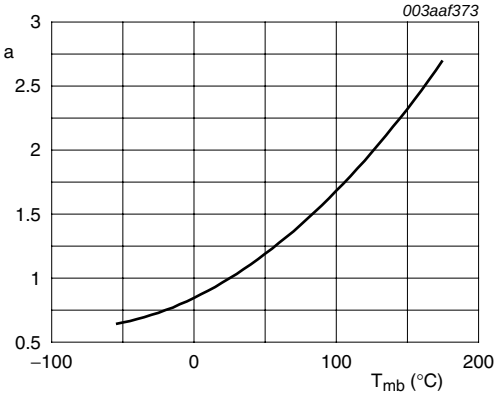
$V_{DS} > I_D \times R_{DSon}$

Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values



$V_{DS} > I_D \times R_{DSon}$

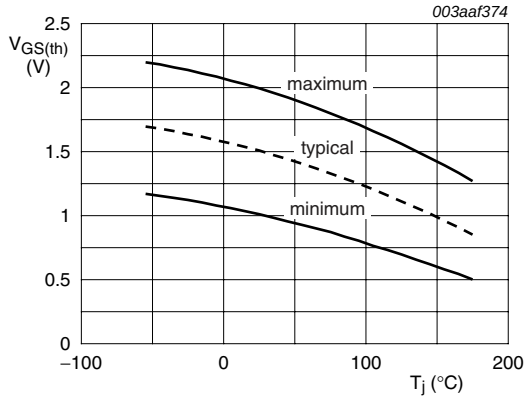
Fig 11. Forward transconductance as a function of drain current; typical values



$$a = \frac{R_{DSon}}{R_{DSon(25°C)}}$$

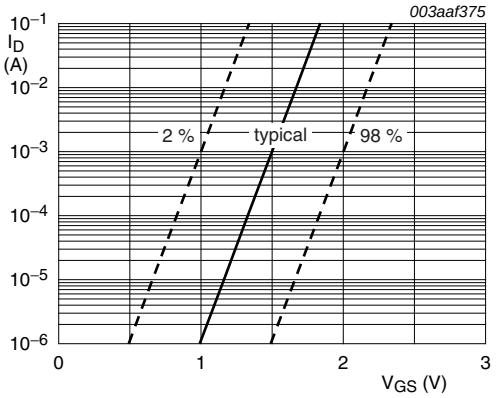
I_D = 25 A; V_{GS} = 5 V

Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature



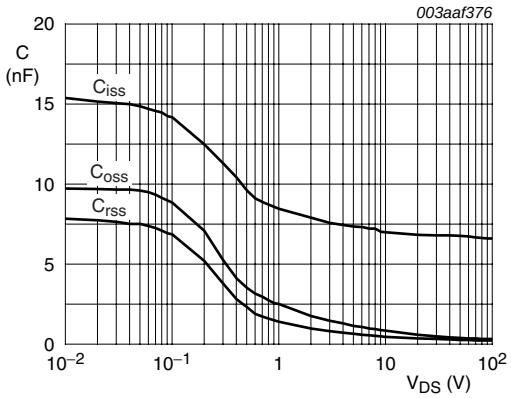
I_D = 1 mA; $V_{DS} = V_{GS}$

Fig 13. Gate-source threshold voltage as a function of junction temperature



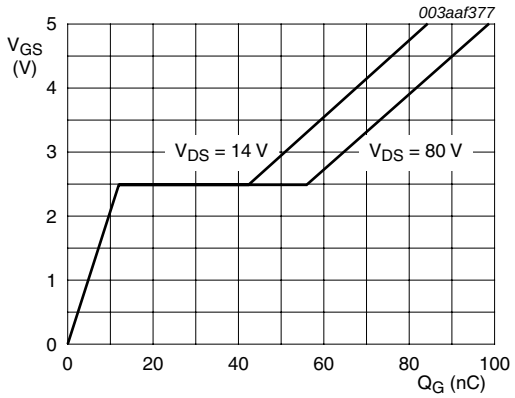
T_j = 25 °C; $V_{DS} = V_{GS}$

Fig 14. Sub-threshold drain current as a function of gate-source voltage



V_{GS} = 0 V; f = 1 MHz

Fig 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

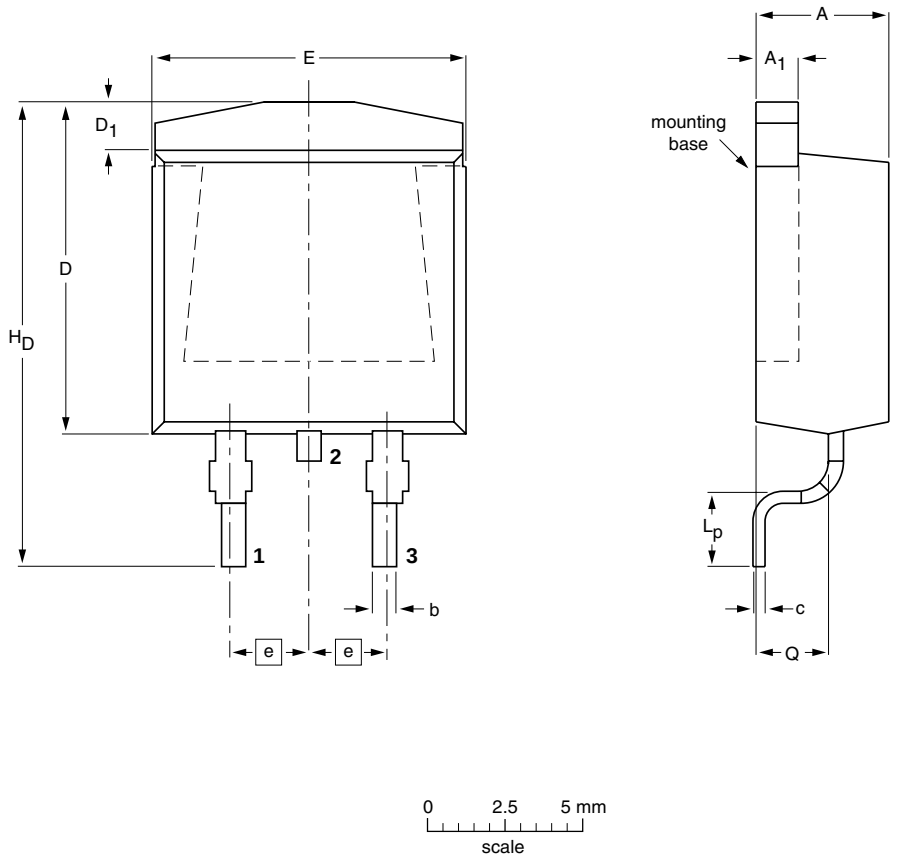


T_j = 25 °C; I_D = 25 A

Fig 16. Gate-source voltage as a function of gate charge; typical values

7. Package outline

Plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) **SOT404**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b	c	D max.	D_1	E	e	L_p	H_D	Q
mm	4.50 4.10	1.40 1.27	0.85 0.60	0.64 0.46	11	1.60 1.20	10.30 9.70	2.54	2.90 2.10	15.80 14.80	2.60 2.20

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT404						~~05-02-11~~ 06-03-16

Fig 17. Package outline SOT404 (D2PAK)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BUK9615-100A v.3	20110419	Product data sheet	-	BUK9515_9615-100A_2
Modifications:	• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • Type number BUK9615-100A separated from data sheet BUK9515_9615-100A_2.			
BUK9515_9615-100A_2	19991101	Product specification	-	BUK9515-100A_1

9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

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11. Contents

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Date of release: 19 April 2011